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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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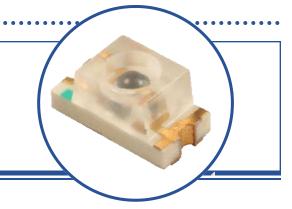


Silicon Phototransistor in Miniature SMT Package



OP522

- High Photo Sensitivity
- Fast Response Time
- 1206 Package Size with Internal Lens

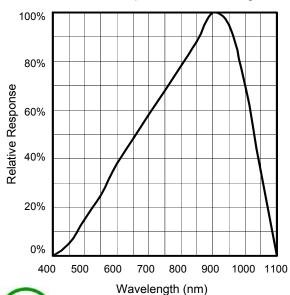


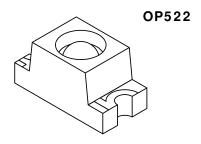
The OP522 is an NPN silicon phototransistor mounted in a miniature SMT package. The device incorporates an integral molded lens which enables a narrow acceptance angle and higher collector currents than devices without lenses. This device is packaged in a 1206 size chip carrier that is compatible with most automated mounting equipment. The OP522 is mechanically and spectrally matched to the OP250 series infrared LEDs.

Applications

- Non-Contact Position Sensing
- Datum detection
- Machine automation
- Optical encoders

Relative Response vs. Wavelength





RoHS

SMT Silicon Phototransistor OP522



Absolute Maximum Ratings

T_A = 25° C unless otherwise noted

Storage Temperature Range	-40° C to +85° C
Operating Temperature Range	-25° C to +85° C
Lead Soldering Temperature	260° C ⁽¹⁾
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Collector Current	20 mA
Power Dissipation	75 mW ⁽²⁾

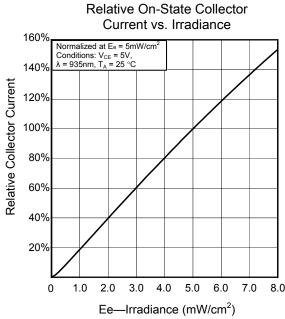
Notes:

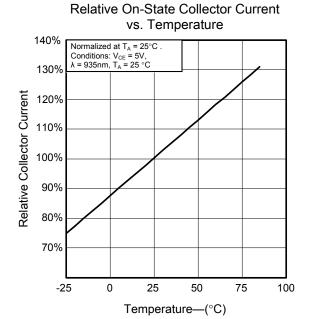
- 1. Solder time less than 5 seconds at temperature extreme.
- 2. De-rate linearly at 2.17 mW/° C above 25° C.

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	CONDITIONS
I _{C(ON)}	On-State Collector Current	0.5			mA	V_{CE} = 5.0V, E_e = 5.0mW/cm ^{2 (3)}
V _{CE(SAT)}	Collector-Emitter Saturation Voltage			0.4	V	$I_C = 100 \mu A, E_e = 2.0 \text{mW/cm}^{2 (3)}$
I _{CEO}	Collector-Emitter Dark Current			100	nA	V_{CE} = 5.0V, E_{e} = 0 ⁽⁴⁾
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	30			V	I _C = 100μA
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5			V	I _E = 100μA
t _r , t _f	Rise and Fall Times		15		μs	I_C = 1mA, R_L = 1K Ω

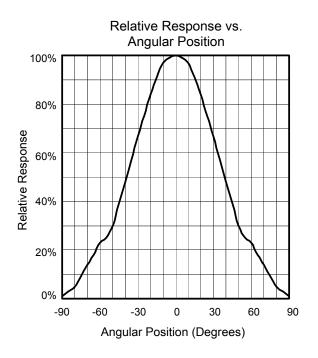
- 3. Light source is an unfiltered GaAs LED with a peak emission wavelength of 935nm and a radiometric intensity level which varies less than 10% over the entire lens surface of the phototransistor being tested.
- 4. To Calculate typical collector dark current in μ A, use the formula $I_{CEO} = 10^{(0.04 \text{ T}_A 3/4)}$ where T_A is the ambient temperature in ° C.

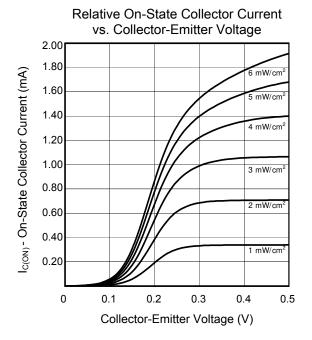




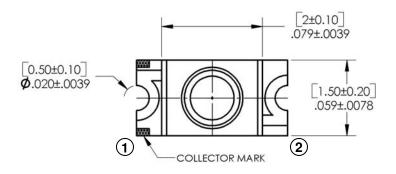
SMT Silicon Phototransistor OP522

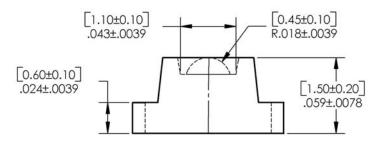


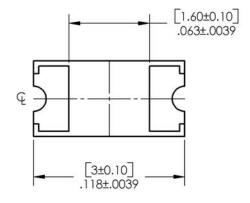






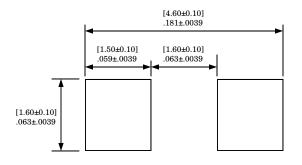






DIMENSIONS ARE IN INCHES AND [MILLIMETERS].

RECOMMENDED SO LDER PADS



PIN	FUNCTION
1	Collector
2	Emitter